	Тур е	ts	Search Text	DBs	Time Stamp	m m e	r D e f	Err
1	BRS	1	metal and metal near mask\$	USPAT; US-PGPUB; EPO; JPO; DERWENT;	2004/09/10 18:17			0
2	BRS	4	high adj K with metal and metal with mask\$ and mask\$ with sacrificial		2004/09/10 18:20			0
3	BRS	11		USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/10 18:20			0
4	BRS	16	with mask\$ and conformal		2004/09/10 18:29		-	0
5	BRS	39		USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/10 18:38			0
6	BRS	0.1		USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/10 18:55			0
7	BRS	6	6300202.URPN.	USPAT	2004/09/10 18:48			0
8	BRS	2	("5885877" "6300202").PN.	USPAT	2004/09/10 18:50			0
9	BRS	30	5885877.URPN.	USPAT	2004/09/10 18:50			0

	е	Hi ts	Search Text	DBs	Time Stamp	o m m e n	D e f i	Errors
10	BRS	21	dielectric with metal and metal with mask\$ and wet near etch\$ with (high near K near dielectric or metal near oxide)	1	2004/09/10 19:00			0
11	BRS	65	dielectric with metal and metal with mask\$ and mask with (sidewall near spacer or conformal\$ or protect\$ or sacrificial\$) and wet with etch\$ with (dielectric or metal near oxide) and etch\$ with metal and stack\$	JPO; DERWENT; IBM_TDB	2004/09/11 17:51			0
12	BRS	10	,	USPAT; US-PGPUB; EPO;	2004/09/11 17:57			0
13	BRS	2	near metal and sidewall with	USPAT; US-PGPUB; EPO;	2004/09/11 18:00			0

	Тур	Hi ts	Search Text	DBs	Time Stamp	m e n	r D e f	E r r
14	BRS	17	indar meral and		2004/09/11 18:06			0
15	BRS	32	•		2004/09/11 18:17			0
16	BRS				2004/09/11 18:21			0
17	BRS	96	(dielectric or oxide) with substrate and metal with (dielectric or oxide) and mask\$ with metal and (sidewall or spacer or protect\$) with mask\$ and high adj k	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/11 18:24			0

	Тур	Hi ts	Search Text	DBs	Time Stamp	Comments	e f i	Errors
18	BRS	24		US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/11 18:38			0
19	BRS	12		JPO; DERWENT; IBM_TDB	2004/09/11 18:43			0
20	BRS	45		US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/11 19:21			0

	Тур	Hi ts	Search Text	DBs	Time Stamp	m m e n	ErrorDefinitio	E r r
21	BRS	2	gate near metal and mask\$ near (metal or gate) and high adj k with gate near dielectric and (cap\$6 or protect\$ or sacrificial) with mask\$ with side\$6	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/11 19:25			0
22	BRS	3	gate near metal and high adj k with gate near dielectric and (cap\$6 or protect\$ or sacrificial) with mask\$ with side\$6	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/11 19:26			0
23	BRS	34	with gate near dielectric and mask\$ with side\$6	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/11 20:36			0
24	BRS	59		USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/11 21:05			0

	Тур	Hi ts	Search Text	DBs	Time Stamp	m m e	e f	Errors
25	BRS	6	gate near metal and gate near dielectric and mask\$ near (metal or gate) and work adj function and (protect\$ or sacrificial or conformal) with metal with mask	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/11 21:13			0
26	BRS	21	gate near metal with gate near dielectric and mask\$ near (metal or gate) and work adj function	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/11 21:20			0
27	BRS	3	etch\$ with gate near metal same mask\$ near (metal or gate) and work adj function and layer with (metal or gate) with mask	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/11 21:27			0
28	BRS	11	etch\$ with gate near metal and mask\$ near (metal or gate) and work adj function and layer with (metal or gate) with mask	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/11 21:28			0

	Тур	Hi	Search Text	DBs	Time Stamp	m m e n	ErrorDefinitio	Error
29	BRS			JPO; DERWENT;	2004/09/11 21:39			0
30	BRS	3	and work adj	JPO; DERWENT;	2004/09/11 21:32			0
31	BRS		(metal or gate) and sacrificial with (metal or gate or mask)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/11 21:33			0
32	BRS		etch\$ with gate near metal same mask\$ near (metal or gate) and protect\$ with (metal or gate) with with mask	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/11 21:34			0
33	BRS	1	etch\$ with gate same mask\$ near gate and sacrificial with metal with mask	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/11 21:41			0
34	BRS	2	etch\$ and gate near stack\$ same mask\$ near gate and sacrificial with gate with mask	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/11 21:45			0

	Тур	Hi ts	Search Text	DBs	Time Stamp	m m e n t	ErrorDefinitio	Error
35	BRS	1	etch\$ near gate same mask\$ near gate and work adj function and sacrificial with gate with mask	US-PGPUB; EPO; JPO; DERWENT;	2004/09/11 21:47			0
36	BRS	3	etch\$ near gate same mask\$ near gate and sacrificial with gate with mask	TDO DEDWENT.	2004/09/11			0
37	IS& R	2	("6063698").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT;	2004/09/11 21:52			0
38	IS& R	2	("6184072").PN.	世 8坪A 〒 PB US-PGPUB; EPO; JPO; DERWENT;	2004/09/11 21:53			0
39	IS& R	2	("6420279").PN.	世島野ATDB US-PGPUB; EPO; JPO; DERWENT;	2004/09/11 21:53			0
40	IS& R	2	("6475874").PN.	世島科ATDB US-PGPUB; EPO; JPO; DERWENT;	2004/09/11 21:54			0
41	IS& R	2	("6514828").PN.	世島科ATDB US-PGPUB; EPO; JPO; DERWENT;	2004/09/11 21:54			0
42	IS& R	2	("6544906").PN.	世島神五平身B US-PGPUB; EPO; JPO; DERWENT;	2004/09/11 21:54			0
43	IS& R	2	("6617209").PN.	世 ይ <u>ሾ</u> ልቸ ጋ B US-PGPUB; EPO; JPO; DERWENT;	2004/09/11 21:55			0
44	IS& R	2	("6620713").PN.	世島幹A平DB US-PGPUB; EPO; JPO; DERWENT;	2004/09/11 21:55			0
45	IS& R	2	("6689675").PN.	世島桝ATPB US-PGPUB; EPO; JPO; DERWENT;	2004/09/11 21:56			0
46	IS& R	2	("6696345").PN.	世界科工事的 US-PGPUB; EPO; JPO; DERWENT;	2004/09/11 21:57			0

	Тур	Hi ts	Search Text	DBs	Time Stamp	m m e	r D e f	E r o r
47	IS& R	2	("6696327").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT;	2004/09/11 21:57			0
48	IS& R	0	! () (也另种ATPB US-PGPUB; EPO; JPO; DERWENT;	2004/09/11 22:00			0
49	IS& R	2	PN.	也多种ATPB US-PGPUB; EPO; JPO; DERWENT;	2004/09/11 22:01			0
50	IS& R	2		也多样A平身B US-PGPUB; EPO; JPO; DERWENT;	2004/09/11 22:01			0
51	IS& R	2	("20030045080"). PN.	也多姓 <u>入</u> 平身B US-PGPUB; EPO; JPO; DERWENT;	2004/09/11 22:01			0
52	BRS	11	mask\$ near side\$7 with sacrificial	也多种A中身B US-PGPUB; EPO; JPO; DERWENT;	2004/09/13 12:19			0
53	BRS	11	•		2004/09/13 12:20			0
54	BRS	11	gate near stack\$ and mask\$ with sacrificial and high adj k and metal	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/13 12:29			0
55	BRS	5	and masks with prespacer and high adj k and metal	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/13 12:32			0
56	BRS	5	gate near stack\$ and mask\$ with prespacer and metal	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/13 12:33			0
57	BRS	15	gate near stack\$ and mask\$ with (sacrificial or prespacer) and gate near metal	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/13 14:18			0

	Тур	Hi ts	Search Text	DBs	Time Stamp	m m e	r D e fi	Error
58	BRS	3	(sacrificial or	USPAT; US-PGPUB; EPO;	2004/09/13 12:47			0
59	BRS		(sacrificial or prespacer) and gate near metal	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/13 12:48			0
60	BRS	14	mask\$ with (sacrificial or prespacer) and gate near metal and high adj k	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/13 13:49			0
61	BRS	3	mask\$ near metal and gate near metal and high adj k and work adj function	USPAT;	2004/09/13 13:53			0
62	BRS	20		JPO; DERWENT; IBM_TDB	2004/09/13 13:54			0
63	BRS		gate near stack\$ and mask\$ with (sacrificial or prespacer or liner or lining) and gate near metal	USPAT; US-PGPUB; EPO;	2004/09/13 14:19			0

	Тур	Hi ts	Search Text	DBs	Time Stamp	o m m e n t s	D e f	Errors
1	BRS	1	near mask\$	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/10 18:17			0
2	BRS	4		USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/10 18:20			0
3	BRS		high adj K with metal and metal with mask\$ and mask\$ with sidewall with spacer	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/10 18:20			0
4	BRS	16	high adj K with metal and metal with mask\$ and conformal	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/10 18:29			0
5	BRS			USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB				0
6	BRS	91	dielectric with metal and metal with mask\$ and wet near etch\$ with dielectric and (dry or plasma) near etch\$ with metal	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/10 18:55			0
7	BRS	6	6300202.URPN.		2004/09/10 18:48			0
8	BRS	2	("5885877" "6300202").PN.		2004/09/10 18:50			0
9	BRS	30	5885877.URPN.	USPAT	2004/09/10 18:50			0

	Тур	Hi ts	Search Text	DBs	Time Star	mp	m m e n	D e f	Errors
10	BRS	21	with (high near K near dielectric or metal near	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/1 19:00	. 0			0
11	BRS		protect\$ or	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/1 17:51	. 1			0
12	BRS	10	high near k with dielectric and metal near gate and mask\$ with metal and sidewall with spacer with mask\$	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/1 17:57	.1			0
13	BRS		sidewall with	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/1 18:00	. 1			0

	Тур	Hi ts	Search Text	DBs	Time Stamp	m m e n t	D	r
14	BRS	17	sidewall with	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/11 18:06			0
15	BRS		etch\$ with metal with stack and sidewall with (spacer or protect\$) with mask\$	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/11 18:17			0
16	BRS	4	and (sidewall or spacer or protect\$) near mask\$	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/11 18:21			О
17	BRS	96	(dielectric or oxide) with substrate and metal with (dielectric or oxide) and mask\$ with metal and (sidewall or spacer or protect\$) with mask\$ and high adj k	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/11 18:24		-	0

	Тур	Hi ts	Search Text	DBs	Time Stamp	m m e n	ErrorDefinitio	rror
18	BRS	24	(dielectric or oxide) with substrate and metal with (dielectric or oxide) and mask\$ with metal and (sidewall or spacer or protect\$) with mask\$ and high adj k and mask\$ with polysilicon	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/11 18:38			0
19	BRS	12	(dielectric or oxide) with substrate and metal with (dielectric or oxide) and mask\$ with metal and side\$6 with mask\$ and high adj k and mask\$ with polysilicon and gate near metal	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/11 18:43			0
20	BRS	45	gate near metal and mask\$ with metal and (cap\$6 or protect\$ or sacrificial) with mask\$ with side\$6 and mask\$ with polysilicon	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/11 19:21			0

	Тур	Hi ts	Search Text	DBs	Time Stamp	m m e n	D e f	Ennon
21	BRS	2	gate near metal and mask\$ near (metal or gate) and high adj k with gate near dielectric and (cap\$6 or protect\$ or sacrificial) with mask\$ with side\$6	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/11 19:25			0
22	BRS	3	gate near metal and high adj k with gate near dielectric and (cap\$6 or protect\$ or sacrificial) with mask\$ with side\$6	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/11 19:26			0
23	BRS	34	gate near metal and high adj k with gate near dielectric and mask\$ with side\$6	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/11 20:36	***************************************		0
24	BRS	59	gate near metal and high adj k with gate near dielectric and mask\$ and work adj function	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/11 21:05			0
25	BRS	6	gate near metal and gate near dielectric and mask\$ near (metal or gate) and work adj function and (protect\$ or sacrificial or conformal) with metal with mask	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/11 21:13	and their man their their communications are also being the common their common and a second		0

	Тур e	Hi ts	Search Text	DBs	Time Stamp	o m m e n t	D e f i	Errors
26	BRS	21	macks near (metal	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/11 21:20			0
27	BRS	3	etch\$ with gate near metal same mask\$ near (metal or gate) and work adj function and layer with (metal or gate) with	Ero, oro,	2004/09/11 21:27			0
28	BRS	11	etchs with gate near metal and masks near (metal or gate) and work adj function and layer with (metal or gate) with	DIO, OIO,	2004/09/11 21:28			0
29	BRS	1	######################################	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/11 21:39			0
30	BRS		gate near metal same mask\$ near (metal or gate) and work adj function and sacrificial with (metal or gate or mask)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/11 21:32			0

	Typ e	Hi ts	Search Text	DBs	Time Stamp	m m e n t s	r D e f	E
39	IS& R	2	("6420279").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/11 21:53			0
40	IS& R	2	("6475874").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/11 21:54			0
41	IS& R	2	("6514828").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/11 21:54			0
42	IS& R	2	("6544906").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/11 21:54			0
43	IS& R	2	("6617209").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/11 21:55			0
44	IS& R	2	("6620713").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/11 21:55			0
45	IS& R	2	("6689675").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/11 21:56			0
46	IS& R	2	("6696345").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/11 21:57			0
47	IS& R	2	("6696327").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/11 21:57			0
48	IS& R	0	(2002/0197790).CC LS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/11 22:00			0
49	IS& R	2	("20020197790").P N.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/11 22:01			0
50	IS& R	2		USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/11 22:01			0
51	IS& R	2	("20030045080").P N.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/11 22:01			0

	Тур	Hi ts	Search Text	DBs		Stamp	o m m e n t s	Error
52	BRS		with cocrificial	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/ 12:19	09/13)		0
53	BRS	ΤŢ	high adj k	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/ 12:20	'09/13)		0
54	BRS		sacrificial and	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/ 12:29	'09/13)		0
55	BRS	5	nigh adj k and	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/ 12:32	/09/13 !		0
56	BRS	5	母名芒ē ^l near stack\$ and mask\$ with prespacer and metal	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/ 12:33	09/13		0
57	BRS	15	gate near stack\$ and mask\$ with (sacrificial or prespacer) and gate near metal	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/ 14:18	/09/13 }		0
58	BRS	3	gate near stack\$ and mask\$ with (sacrificial or prespacer) and gate near metal and high adj k	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/ 12:47	/09/13 /		0
59	BRS	10 8	mask\$ with (sacrificial or prespacer) and gate near metal	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/ 12:48	'09/13 }		0
60	BRS	14	prespacer) and	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/ 13:49	'09/13)		0

	Тур е	Hi ts	Search Text	DBs	Time Stamp	o m m e n	D e f i	
61	BRS		metal and high	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/13 13:53			0
62	BRS		work adi function	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/13 13:54			0
63	BRS	19	nragnacar or	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/13 14:19			0

	Тур е	Hi ts	Search Text	DBs	Time Stamp	m m e n	ErrorDefinitio	Enron
31	BRS	6	sacrificial with (metal or gate or mask)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/11 21:33			0
32	BRS			USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/11 21:34	NAME NAMES 188000 188000 CATAC TRANSPORTATION OF THE STATE OF THE STAT	10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 10000 100000	0
33	BRS	1	etch\$ with gate same mask\$ near gate and sacrificial with metal with mask	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/11 21:41	A seron cares erries of city filters are at \$1,150 to 100		0
34	BRS	2	etch\$ and gate near stack\$ same mask\$ near gate and sacrificial with gate with mask	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/11 21:45			0
35	BRS	1	etch\$ near gate same mask\$ near gate and work adj function and sacrificial with gate with mask	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/11 21:47			0
36	BRS	3	etch\$ near gate same mask\$ near gate and sacrificial with gate with mask	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/11 22:10			0
37	IS& R	2	("6063698").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/11 21:52			0
38	IS& R	2	("6184072").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/11 21:53			0